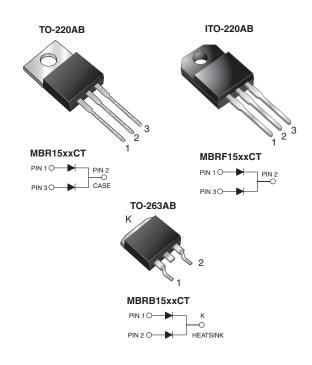


Vishay General Semiconductor

Dual Common-Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)} 7.5 A x 2					
V _{RRM}	35 V to 60 V				
I _{FSM}	150 A				
V _F	0.57 V, 0.65 V				
T _J max.	150 °C				

FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	٧	
Working peak reverse voltage	V _{RWM}	35	45	50	60	V	
Maximum DC blocking voltage		35	45	50	60	V	
$\begin{array}{ll} \mbox{Maximum average forward rectified} & \mbox{total device} \\ \mbox{current at } T_{C} = 105 \ ^{\circ}\mbox{C} & \mbox{per diode} \end{array}$	I _{F(AV)}	15 7.5				A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150				A	
Peak repetitive reverse surge current per diode at t_p = 2.0 $\mu s,1$ kHz	I _{RRM}	1.0 0.5			.5	A	
Voltage rate of change (rated V _R)	dV/dt	10 000				V/µs	
Operating junction temperature range	TJ	- 65 to + 150			°C		

Document Number: 88670 Revision: 08-Nov-07 For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



ROHS COMPLIANT

Vishay General Semiconductor



MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL MBR1535CT MBR1545CT MBR1550CT MBR1560CT					UNIT	
Storage temperature range	T _{STG}	- 65 to + 175			°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 7.5 A I _F = 7.5 A I _F = 15 A I _F = 15 A		V _F	- 0.57 0.84 0.72		0. 0.	-	v
Maximum instantaneous reverse current at rated DC blocking voltage per diode ⁽¹⁾		T _C = 25 °C T _C = 125 °C	I _R	0.1 15		1. 5	-	mA

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER SYMBOL MBR MBRF MBRB						
Maximum thermal resistance per diode	$R_{ heta JA} \ R_{ heta JC}$	60 3.0	- 5.0	60 3.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR1545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/81	1.35	81	800/reel	Tape reel		
TO-220AB	MBR1545CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/81 (1)	1.35	81	800/reel	Tape reel		

Note:

(1) Automotive grade AEC Q101 qualified



MBR1535CT - MBR1545CT

MBR1550CT & MBR1560CT

Vishay General Semiconductor

= 125 °C

100

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

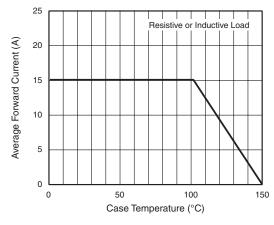


Figure 1. Forward Current Derating Curve

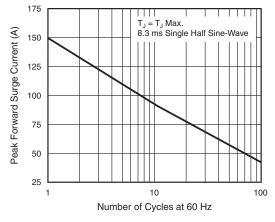


Figure 2. Maximum Non-Repetitive Peak Forward Surge **Current Per Diode**

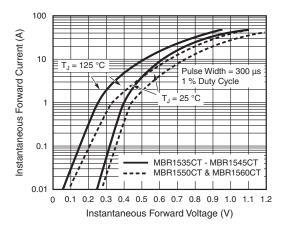
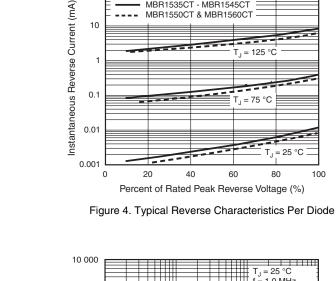


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

Document Number: 88670 Revision: 08-Nov-07

Downloaded from Elcodis.com electronic components distributor

For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



100

10

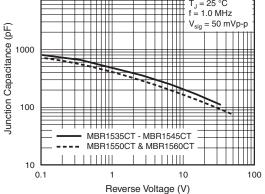
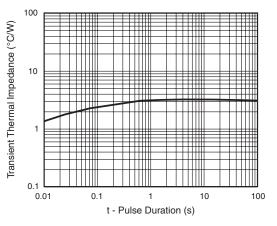


Figure 5. Typical Junction Capacitance Per Diode

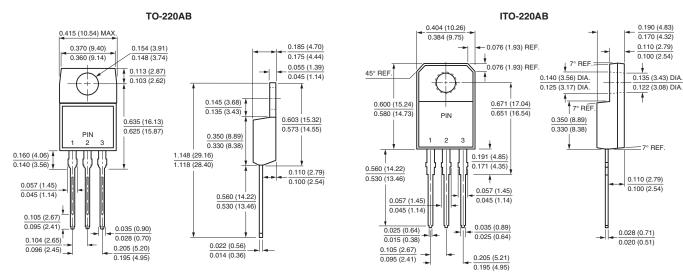




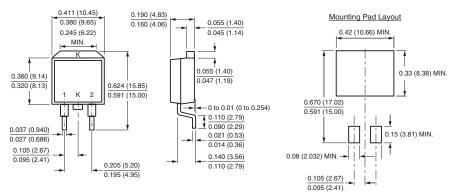
Vishay General Semiconductor



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB



www.vishay.com



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.